

MIP508

Silicon MOS IC

■ Features

- 3-pin intelligent power device
 - Five protective functions (over-current, over-voltage, short circuit load, over heat, ESD) are integrated
 - Acceptable both AC and DC power supply

■ Applications

- For lamp and solenoid drive

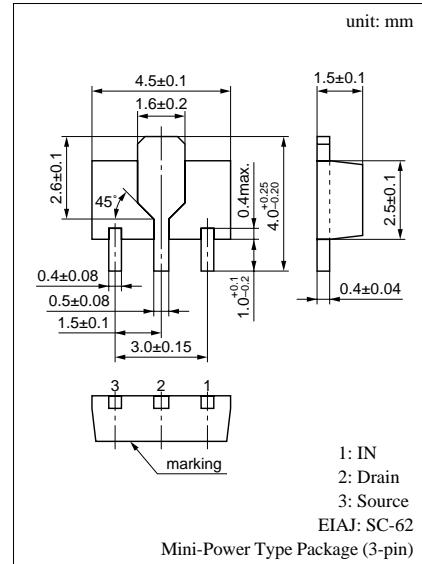
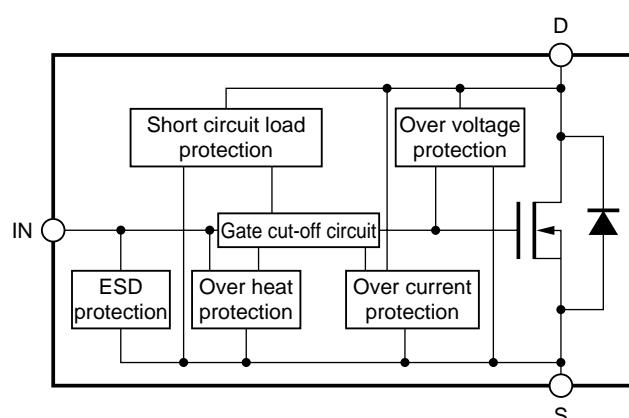
■ Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Ratings	Unit
Output voltage	V _{DS}	40	V
Output peak current	I _{OP}	±3	A
Output current	T _C = 25°C	I _O	A
	T _C = 85°C		
Input voltage	V _{IN}	-0.5 to 6	V
Input current	I _{IN}	±5	mA
Drain clamp energy	E _{CLP}	24* ¹	mJ
Allowable power dissipation	T _C = 25°C	P _D	W
	T _a = 25°C		
	T _a = 85°C		
Channel temperature	T _{ch}	-40 to +150	°C
Storage temperature	T _{stg}	-55 to +150	°C

*¹ L_c = 10mH, V_{DD} = 20V, I_L = 2.19A, T_C = 25°C, 1pulse

*² Mounting on the PCB (the copper foil of the drain portion should have a area of 100mm² or more and the board thickness should be 1.7mm.)

■ Block Diagram



■ Electrical Characteristics ($T_C = 25 \pm 3^\circ\text{C}$)

Parameter	Symbol	Conditions	min	typ	max	Unit
Drain to Source ON-resistance	$R_{DS(on)}$	$V_{IN} = 5\text{V}$, $I_{DS} = 1\text{A}$		0.5	1.1	Ω
Drain to Source ON-voltage	$V_{DS(on)}$	$V_{IN} = 5\text{V}$, $I_{DS} = 1\text{A}$		0.5	1.1	V
Drain clamp voltage	$V_{DS(CL)}$	$V_{IN} = 0$, $I_{DS} = 3\text{mA}$	40	49	58	V
Drain OFF current (1)	$I_{DS(off)1}$	$V_{IN} = 0$, $V_{DS} = 12\text{V}$		50	120	μA
Drain OFF current (2)	$I_{DS(off)2}$	$V_{IN} = 0$, $V_{DS} = 16\text{V}$		70	180	μA
Input voltage (High)	$V_{IN(H)}$	$I_{DS} = 1\text{A}$	4			V
Input voltage (Low)	$V_{IN(L)}$	$I_{DS} = 1\text{mA}$			0.8	V
Input current	$I_{IN(on)}$	$V_{IN} = 5\text{V}$, $V_{DS} = 0$		0.15	0.5	mA
Over current protection limit	I_{OCP}	$V_{IN} = 5\text{V}$	2	3		A
Short circuit load protection limit	$V_{DS(SHT)}$	$V_{IN} = 5\text{V}$	2	4	10	V

Note: The oscillation of the output current is caused when the drain voltage exceeds the short circuit load detection voltage under the ON state of output.

■ Electrical Characteristics ($T_C = 25 \pm 3^\circ\text{C}$)

Parameter	Symbol	Conditions	min	typ	max	Unit
Over heat protection temperature	T_{SHD}	$V_{IN} = 5\text{V}$	160	190		$^\circ\text{C}$

Note 1: The above values of characteristics are not guaranteed values and are only references for designing.

Note 2: If the chip temperature exceeds the "Over Heat Protection Temperature", output current is shut down.

■ Timing Chart

